

ESH3B-M3, ESH3C-M3, ESH3D-M3

Vishay General Semiconductor

Surface Mount Ultrafast Plastic Rectifier



DO-214AB (SMC)

PRIMARY CHARACTERISTICS					
I _{F(AV)} 3.0 A					
V _{RRM}	100 V, 150 V, 200 V				
t _{rr}	25 ns				
V _F	0.90 V				
T _J max.	175 °C				
Package	DO-214AB (SMC)				
Diode variations	Single die				

FEATURES

- Glass passivated pellet chip junction
- Ideal for automated placement
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer, and automotive.

MECHANICAL DATA

Case: DO-214AB (SMC) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	ESH3B	ESH3C	ESH3D	UNIT	
Device marking code		EHB	EHC	EHD		
Maximum repetitive peak reverse voltage	V _{RMM}	100	150	200		
Maximum RMS voltage	V _{RMS}	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	100	150	200		
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	3.0				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	125			A	
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175			°C	

Pb

RoHS COMPLIANT HALOGEN FREE



Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Maximum instantaneous forward voltage	I _F = 3 A		V _F ⁽¹⁾	0.90	V	
Maximum DC reverse current at rated DC blocking voltage		T _A = 25 °C	I_	5.0	μA	
		T _A = 125 °C	- I _R	150		
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		t _{rr}	25		
Typical reverse recovery time	$ I_F = 3 \text{ A}, V_R = 30 \text{ V}, \\ dI/dt = 50 A/\mu \text{s}, I_{rr} = 10 \% I_{RM} $	T _J = 25 °C	- t _{rr}	40	ns	
		T _J = 100 °C		55		
Typical stored charge	I _F = 3 A, V _B = 30 V,	T _J = 25 °C	– Q _{rr}	25	nC	
	dl/dt = 50 A/ μ s, I _{rr} = 10 % I _{RM}	T _J = 100 °C		60		
Typical junction capacitance	4.0 V, 1 MHz		CJ	70	pF	

Note

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	ESH3B ESH3C ESH3D		UNIT	
Typical thermal registeres	R _{0JA} ⁽¹⁾	50			°C/W
Typical thermal resistance	$R_{ ext{ heta}JL}$ ⁽¹⁾		C/W		

Note

 $^{(1)}\,$ Units mounted on PCB with 12.0 mm x 12.0 mm land areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH3D-M3/57T	0.211	57T	850	7" diameter plastic tape and reel		
ESH3D-M3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel		

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

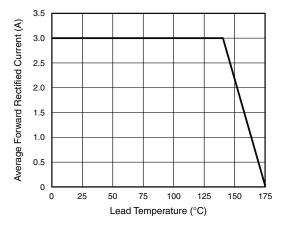


Fig. 1 - Maximum Forward Current Derating Curve

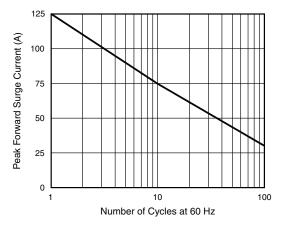


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

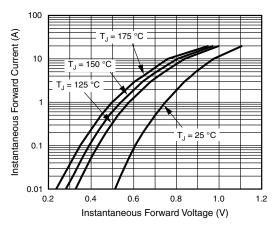


Fig. 3 - Typical Instantaneous Forward Characteristics

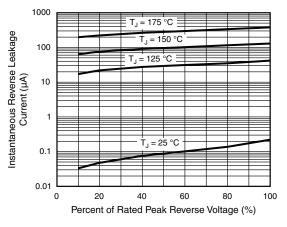


Fig. 4 - Typical Reverse Leakage Characteristics

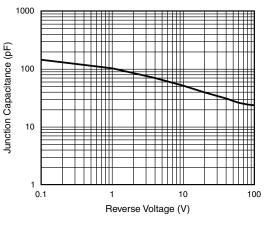


Fig. 5 - Typical Junction Capacitance

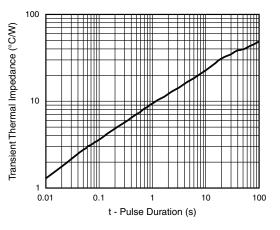


Fig. 6 - Typical Transient Thermal Impedance

Revision: 25-Feb-16

3

Document Number: 88461

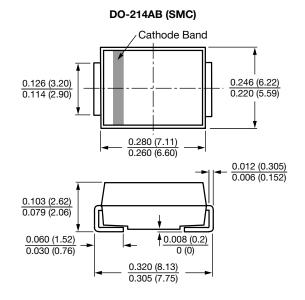
For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



ESH3B-M3, ESH3C-M3, ESH3D-M3

Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout - 0.185 (4.69) MAX. 0.126 (3.20) MIN 0.060 (1.52) MIN. --- 0.320 (8.13) REF. ----

Revision: 25-Feb-16 Document Number: 88461 4 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

ESH3B-M3/57T ESH3C-M3/57T ESH3B-M3/9AT ESH3C-M3/9AT ESH3D-M3/57T ESH3D-M3/9AT